

TECHNICAL DATA DATA SHEET 266, REV -

# HERMETIC ULTRAFAST RECOVERY RECTIFIER

DESCRIPTION: 150 VOLT, 40 AMP, 35 NANOSECOND, HERMETIC RECTIFIER IN A TO-254 PACKAGE.

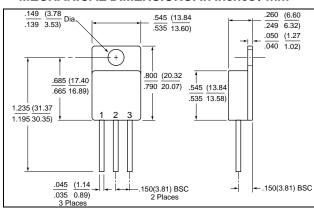
MAX RATINGS/ELECTRICAL CHARACTERISTICS ALL RATINGS ARE AT TA = 25 °C UNLESS OTHERWISE SPECIFIED.

**RATING** SYMBOL MAX. **UNITS** PIV PEAK INVERSE VOLTAGE (PER LEG) 150 Volts MAXIMUM FORWARD VOLTAGE DROP (PER LEG) (I<sub>f</sub> = 10 Amps) Volts  $V_f$ 1.0  $I_{\rm F} = 10 \, A, T_{\rm A} = 25 \, {\rm C}^{\circ}$ 0.83  $I_F = 10A, T_A = 125 \text{ C}^{\circ}$ MAXIMUM DC OUTPUT CURRENT (T<sub>C</sub> = 100 °C)  $I_{O}$ 40 Amps PEAK SINGLE CYCLE SURGE CURRENT t<sub>p</sub> = 8.3 msec. 300 Amps  $I_{\text{FSM}}$ MAXIMUM REVERSE RECOVERY TIME ( $I_f = 0.5A$ ,  $I_r = 1.0A$ ,  $I_{rr} = 0.25A$ ) 35  $t_{rr}$ nsec MAXIMUM REVERSE CURRENT I, @ PIV (PER LEG)  $I_r$ 10 μΑ mΑ 1.0 MAXIMUM THERMAL RESISTANCE (PER LEG) 2.3  $R_{\theta JC}$ °C/W MAXIMUM OPERATING TEMPERATURE RANGE -65 to °C +200 JUNCTION CAPACITANCE V<sub>R</sub> = 10Vdc, f = 1mHz  $C_J$ 150 pF  $V_{SIG} = 50 \text{mV (p-p) (Max)}$ 

<sup>\*</sup> Suffix R denotes common anode version.

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# **MECHANICAL DIMENSIONS: In Inches / mm**

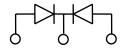


TO-254

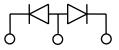
### **PINOUT TABLE**

TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (R)	CATHODE 1	COMMON ANODE	CATHODE 2

# **SCHEMATIC**



**COMMON CATHODE** 



**COMMON ANODE** 



#### **TECHNICAL DATA**

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